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Kind regards,

Team Nexperia

# **PDTA115T series**

PNP resistor-equipped transistors; R1 = 100 k $\Omega$ , R2 = open

Rev. 05 — 2 September 2009

Product data sheet

## 1. Product profile

#### 1.1 General description

PNP resistor-equipped transistors.

Table 1. Product overview

Type number	Package	Package		
	NXP	JEITA		
PDTA115TE	SOT416	SC-75	PDTC115TE	
PDTA115TK	SOT346	SC-59	PDTC115TK	
PDTA115TM	SOT883	SC-101	PDTC115TM	
PDTA115TS[1]	SOT54 (TO-92)	SC-43A	PDTC115TS	
PDTA115TT	SOT23	-	PDTC115TT	
PDTA115TU	SOT323	SC-70	PDTC115TU	

<sup>[1]</sup> Also available in SOT54A and SOT54 variant packages (see Section 2)

#### 1.2 Features

- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs

#### 1.3 Applications

- General purpose switching and amplification
- Inverter and interface circuits

#### Circuit drivers

#### 1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	-50	V
I <sub>O</sub>	output current (DC)		-	-	-100	mA
R1	bias resistor 1 (input)		70	100	130	kΩ



# 2. Pinning information

Table 3. Pinning

Pin	Description	Simplified outline	Symbol
SOT54			
1	input (base)		
2	output (collector)		2
3	GND (emitter)	001aab347	1 R1 3

0		-	_	А	A
2	u	"	ວ	4	А

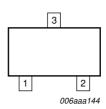
1	input (base)		
2	output (collector)		1 2
3	GND (emitter)	001aab348	1 R1 3
			006aaa217

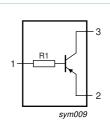
#### SOT54 variant

1	input (base)		
2	output (collector)	<b>T</b> :	2
3	GND (emitter)	1 cm 1 001aab447	1 R1 3
			006aaa217

#### SOT23, SOT323, SOT346, SOT416

1	input (base)
2	GND (emitter)
3	output (collector)

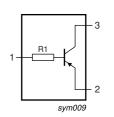




#### **SOT883**

1	input (base)
2	GND (emitter)
3	output (collector)





PDTA115T\_SER\_5

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# 3. Ordering information

Table 4. Ordering information

Type number	Package					
	Name	Description	Version			
PDTA115TE	SC-75	plastic surface mounted package; 3 leads	SOT416			
PDTA115TK	SC-59	plastic surface mounted package; 3 leads	SOT346			
PDTA115TM	SC-101	leadless ultra small plastic package; 3 solder lands; body $1.0\times0.6\times0.5~\text{mm}$	SOT883			
PDTA115TS[1]	SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54			
PDTA115TT	-	plastic surface mounted package; 3 leads	SOT23			
PDTA115TU	SC-70	plastic surface mounted package; 3 leads	SOT323			

<sup>[1]</sup> Also available in SOT54A and SOT54 variant packages (see Section 2 and Section 9).

## 4. Marking

Table 5. Marking codes

Type number	Marking code <sup>[1]</sup>
PDTA115TE	12
PDTA115TK	11
PDTA115TM	E8
PDTA115TS	TA115T
PDTA115TT	*AC
PDTA115TU	*11

<sup>[1] \* = -:</sup> made in Hong Kong

<sup>\* =</sup> p: made in Hong Kong

<sup>\* =</sup> t: made in Malaysia

<sup>\* =</sup> W: made in China

## 5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

			•		
Symbol	Parameter	Conditions	Min	Max	Unit
$V_{\text{CBO}}$	collector-base voltage	open emitter	-	-50	V
$V_{CEO}$	collector-emitter voltage	open base	-	-50	V
$V_{EBO}$	emitter-base voltage	open collector	-	-5	V
Io	output current (DC)		-	-100	mA
I <sub>CM</sub>	peak collector current		-	-100	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$			
	SOT416		<u>[1]</u> _	150	mW
	SOT346		<u>[1]</u> _	250	mW
	SOT883		[2][3]	250	mW
	SOT54		<u>[1]</u> _	500	mW
	SOT23		<u>[1]</u> _	250	mW
	SOT323		<u>[1]</u> _	200	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
T <sub>j</sub>	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C

<sup>[1]</sup> Refer to standard mounting conditions.

#### 6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air				
	SOT416		<u>[1]</u> -	-	833	K/W
	SOT346		<u>[1]</u> -	-	500	K/W
	SOT883		[2][3]	-	500	K/W
	SOT54		<u>[1]</u> -	-	250	K/W
	SOT23		<u>[1]</u> -	-	500	K/W
	SOT323		<u>[1]</u> -	-	625	K/W

<sup>[1]</sup> Refer to standard mounting conditions.

<sup>[2]</sup> Reflow soldering is the only recommended soldering method.

<sup>[3]</sup> Refer to SOT883 standard mounting conditions; FR4 printed-circuit board with 60 µm copper strip line.

<sup>[2]</sup> Reflow soldering is the only recommended soldering method.

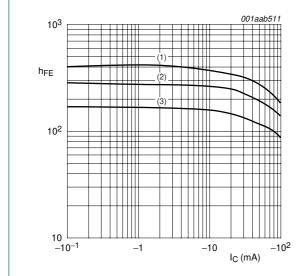
<sup>[3]</sup> Refer to SOT883 standard mounting conditions; FR4 printed-circuit board with 60 µm copper strip line.

## 7. Characteristics

Table 8. Characteristics

T<sub>amb</sub> = 25 °C unless otherwise specified

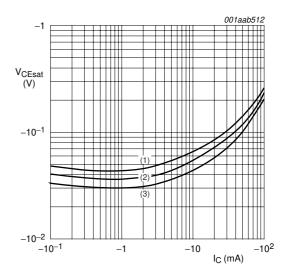
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$I_{CBO}$	collector-base cut-off current	$V_{CB} = -50 \text{ V}; I_E = 0 \text{ A}$	-	-	-100	nA
I <sub>CEO</sub>	collector-emitter	$V_{CE} = -30 \text{ V}; I_B = 0 \text{ A}$	-	-	<b>–1</b>	μΑ
cut-off current		$V_{CE} = -30 \text{ V}; I_{B} = 0 \text{ A};$ $T_{j} = 150 \text{ °C}$	-	-	-50	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_C = 0 \text{ A}$	-	-	-100	nA
h <sub>FE</sub>	DC current gain	$V_{CE} = -5 \text{ V}; I_{C} = -1 \text{ mA}$	100	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = -5 \text{ mA}; I_B = -0.25 \text{ mA}$	-	-	-150	mV
R1	bias resistor 1 (input)		70	100	130	kΩ
C <sub>c</sub>	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz	-	-	3	pF





- (1)  $T_{amb} = 100 \, ^{\circ}C$ .
- (2)  $T_{amb} = 25 \, ^{\circ}C$ .
- (3)  $T_{amb} = -40 \, ^{\circ}C$ .

Fig 1. DC current gain as a function of collector current; typical values



 $I_{\rm C}/I_{\rm B} = 20.$ 

- (1)  $T_{amb} = 100 \, ^{\circ}C$ .
- (2)  $T_{amb} = 25$  °C.
- (3)  $T_{amb} = -40 \, ^{\circ}C$ .

Fig 2. Collector-emitter saturation voltage as a function of collector current; typical values

# 8. Package outline

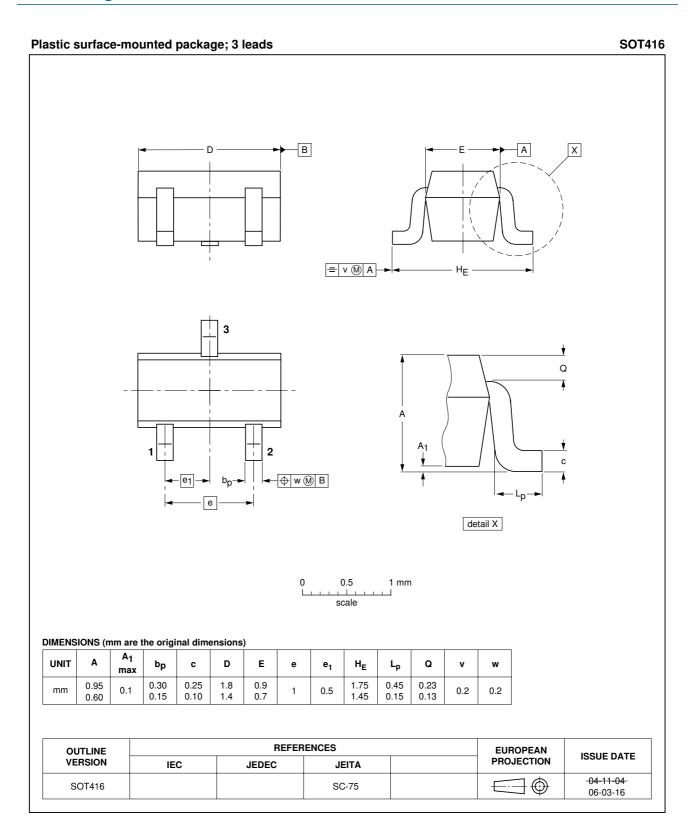


Fig 3. Package outline SOT416 (SC-75)

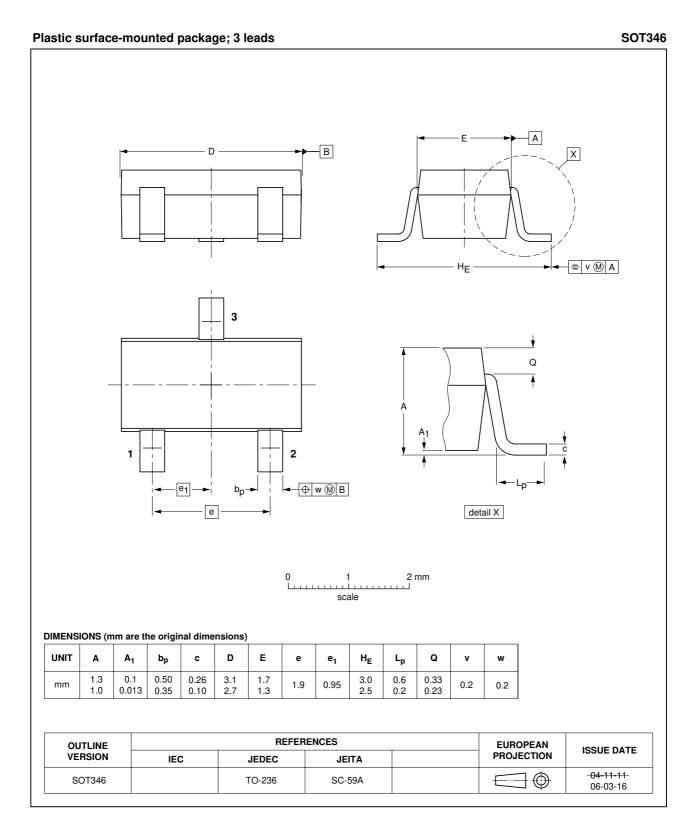


Fig 4. Package outline SOT346 (SC-59/TO-236)

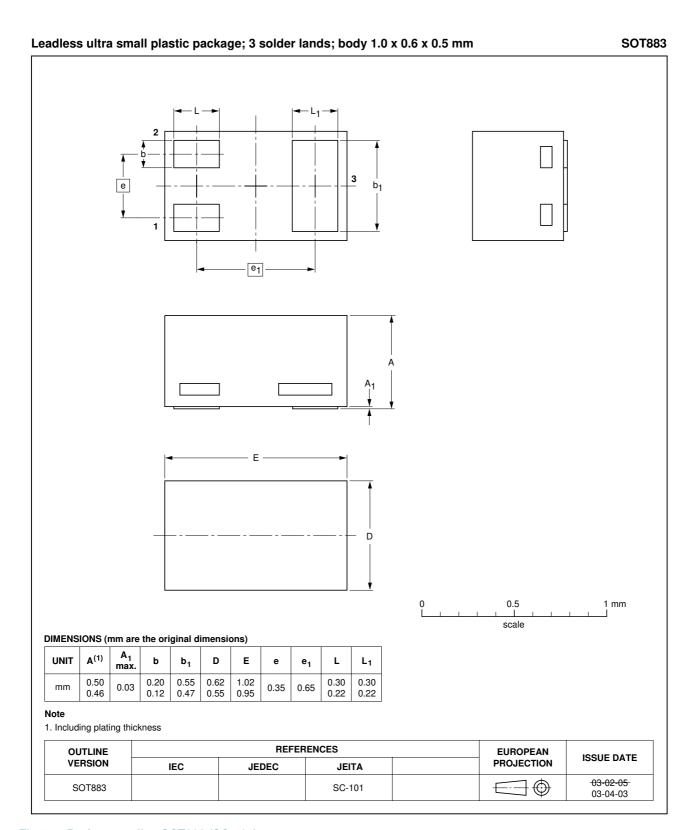
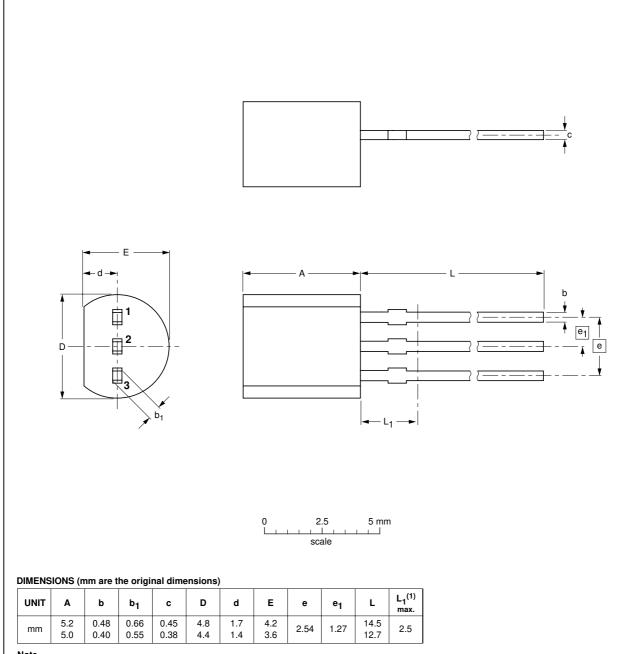


Fig 5. Package outline SOT883 (SC-101)

#### Plastic single-ended leaded (through hole) package; 3 leads

SOT54



#### Note

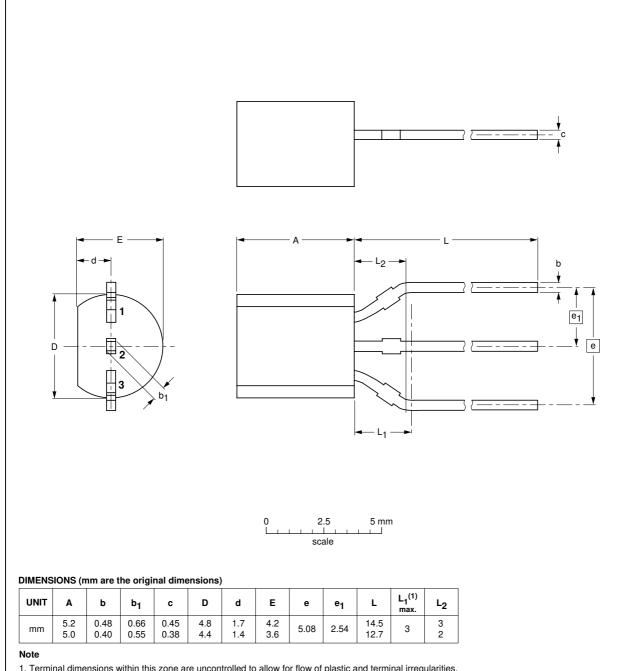
1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT54		TO-92	SC-43A			<del>-04-06-28</del> 04-11-16

Fig 6. Package outline SOT54 (SC-43A/TO-92)

#### Plastic single-ended leaded (through hole) package; 3 leads (wide pitch)

SOT54A



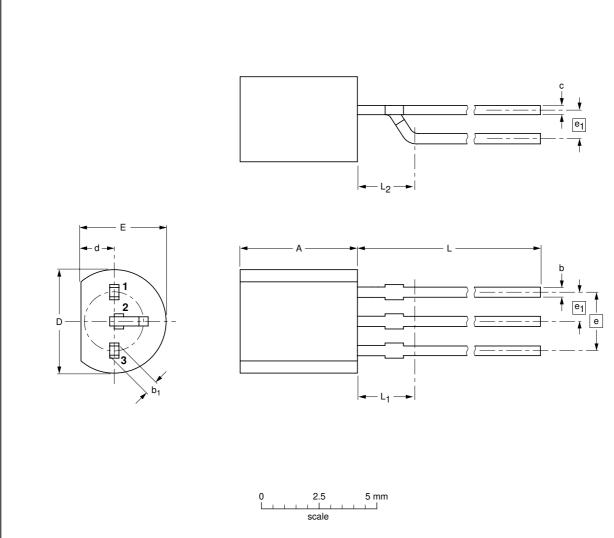
1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE		REFEF	EUROPEAN	IOOUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT54A						<del>97-05-13</del> 04-06-28

Fig 7. Package outline SOT54A

# Plastic single-ended leaded (through hole) package; 3 leads (on-circle)

**SOT54** variant



#### **DIMENSIONS** (mm are the original dimensions)

UNIT	A	b	b <sub>1</sub>	С	D	d	E	е	e <sub>1</sub>	L	L <sub>1</sub> <sup>(1)</sup> max	L <sub>2</sub> max
mm	5.2 5.0	0.48 0.40	0.66 0.55	0.45 0.38	4.8 4.4	1.7 1.4	4.2 3.6	2.54	1.27	14.5 12.7	2.5	2.5

#### Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT54 variant						<del>-04-06-28</del> 05-01-10

Fig 8. Package outline SOT54 variant

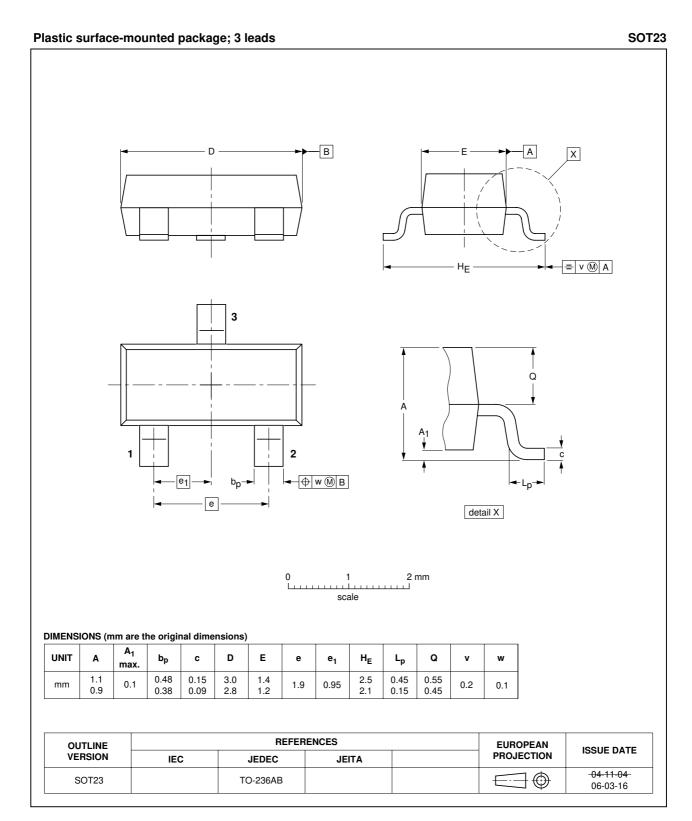


Fig 9. Package outline SOT23 (TO-236AB)

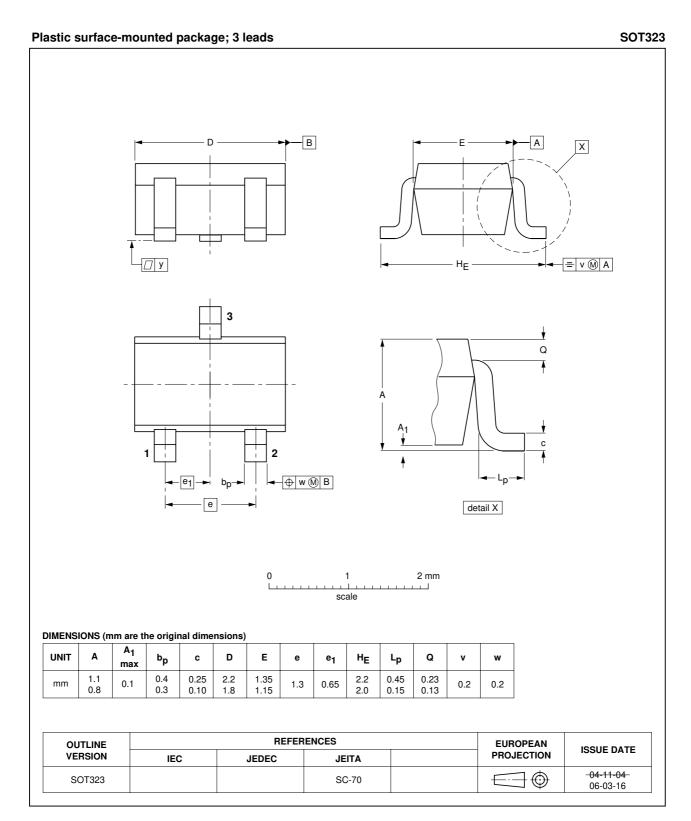


Fig 10. Package outline SOT323 (SC-70)

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PNP resistor-equipped transistors; R1 = 100 kΩ, R2 = open

# 9. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code. [1]

Type number	Package	Description	Packing of	Packing quantity			
			3000	5000	10000		
PDTA115TE	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-135		
PDTA115TK	SOT346	4 mm pitch, 8 mm tape and reel	-115	-	-135		
PDTA115TM	SOT883	2 mm pitch, 8 mm tape and reel	-	-	-315		
PDTA115TS	SOT54	bulk, straight leads	-	-412	-		
	SOT54A	tape and reel, wide pitch	-	-	-116		
	SOT54A	tape ammopack, wide patch	-	-	-126		
	SOT54 variant	bulk, delta pinning	-	-112	-		
PDTA115TT	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-235		
PDTA115TU	SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-135		

<sup>[1]</sup> For further information and the availability of packing methods, see Section 12.

# 10. Revision history

#### Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PDTA115T_SER_5	20090902	Product data sheet	-	PDTA115T_SER_4
Modifications:		NXP Semiconductors, re made to the technical		
	<ul> <li>Figure 3 "Packa"</li> </ul>	age outline SOT416 (SC-75	o)": updated	
	<ul> <li>Figure 4 "Packa"</li> </ul>	age outline SOT346 (SC-59	9/TO-236)": updated	
	<ul> <li>Figure 9 "Packa"</li> </ul>	age outline SOT23 (TO-236	SAB)": updated	
	• Figure 10 "Pack	kage outline SOT323 (SC-7	7 <u>0)"</u> : updated	
PDTA115T_SER_4	20050405	Product data sheet	-	PDTA115TT_3
PDTA115TT_3	20040907	Objective data sheet	-	PDTA115TT_2
PDTA115TT_2	20040518	Objective data sheet	-	PDTA115TT_1
PDTA115TT_1	20040323	Objective data sheet	-	-

## 11. Legal information

#### 11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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# **PDTA115T series**

PNP resistor-equipped transistors; R1 = 100 k $\Omega$ , R2 = open

#### 13. Contents

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